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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/613,931	07/03/2003	James R. Oikari	FSI0111/US	4635
7590 08/24/2005		EXAM	EXAMINER	
Kevin J. Hubbard			CARRILLO, BIBI SHARIDAN	
Kagan Binder, PLLC			ART UNIT	PAPER NUMBER
Maple Island Building, Suite 200 221 Main Street North		1746		
Stillwater, MN	Stillwater, MN 55082 DATE MAILED: 08/2			5

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
· ·	10/613,931	OIKARI ET AL.	
Office Action Summary	Examiner	Art Unit	
	Sharidan Carrillo	1746	
The MAILING DATE of this communication Period for Reply	appears on the cover sheet w	ith the correspondence address	
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATIO - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a If NO period for reply is specified above, the maximum statutory per - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the magnitude of the part of of the pa	N. R 1.136(a). In no event, however, may a reply within the statutory minimum of thi riod will apply and will expire SIX (6) MOI atute, cause the application to become A	reply be timely filed by (30) days will be considered timely. ITHS from the mailing date of this communication BANDONED (35 U.S.C. § 133).	on.
Status			
1) Responsive to communication(s) filed on 3	<u>1 May 2005</u> .		
2a) This action is FINAL . 2b) ⊠ T	his action is non-final.		
3) Since this application is in condition for allocation accordance with the practice under the practice under the practice.	•	·	İS
Disposition of Claims			
4) Claim(s) 1-3, 6,-7, 9, 26-36 is/are pending in 4a) Of the above claim(s) is/are without 5) Claim(s) is/are allowed. 6) Claim(s) 1-3,6,7,9 and 26-36 is/are rejected to. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and are subject to restriction and are subjected to by the Example 10) The specification is objected to by the Example 10) The drawing(s) filed on is/are: a) are subjected to by the Example 10) The drawing(s) filed on is/are: a) are subjected to by the Example 11) The oath or declaration is objected to by the Example 11) The oath or declaration is objected to by the Example 11) The oath or declaration is objected to by the Example 11) The oath or declaration is objected to by the	drawn from consideration. d. d/or election requirement. hiner. accepted or b) objected to the drawing(s) be held in abeya rection is required if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 CFR 1.121((d).
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for fore a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority document application from the International Bure * See the attached detailed Office action for a second content of the priority document application from the International Bure * See the attached detailed Office action for a second content of the priority document application from the International Bure	ents have been received. ents have been received in A priority documents have been reau (PCT Rule 17.2(a)).	pplication No received in this National Stage	
Attachment(s)		·	
1) X Notice of References Cited (PTO-892)		Summary (PTO-413)	
 Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/Paper No(s)/Mail Date 		s)/Mail Date nformal Patent Application (PTO-152) 	

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DETAILED ACTION

Claim Rejections - 35 USC § 112

- 1. The following is a quotation of the second paragraph of 35 U.S.C. 112:
 - The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 2. Claim 29 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 29 is indefinite because it recites duplicative rinsing steps with ionized clean dry air.

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 4. Claim 33 is rejected under 35 U.S.C. 102(b) as being anticipated by Blackwood (4132567).

Blackwood teaches cleaning of wafers in a processing chamber followed by drying with ionized nitrogen gas to eliminate static electric charge from the wafer. In col. 6-7 bridging, Blackwood teaches introducing ionized nitrogen gas into the bowl during the rinsing cycle. In the reference to the gaseous antistatic agent and the drying enhancement substance, the examiner considers ionized nitrogen gas to read on both limitations.

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Claim Rejections - 35 USC § 103

- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
 - 1. Determining the scope and contents of the prior art.
 - 2. Ascertaining the differences between the prior art and the claims at issue.
 - 3. Resolving the level of ordinary skill in the pertinent art.
 - 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 7. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 8. Claims 1-3, 6, 9, 26-28, 30, 32, and 34 are rejected under 35 U.S.C. 103(a) as being unpatentable over Blackwood et al. (4132567) in view of Tomimori et al. (US2003/0013310).

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In reference to claims 1 and 26, Blackwood et al. teach the invention substantially as claimed with the exception of the antistatic agent comprising CO2. Blackwood further fails to teach rinsing with CO2. Tomimori et al. teach drying with nitrogen gas or CO2 gas and further teaches treating the wafer with CO2 in combination with water to decrease the electric charge on the wafer surface.

It would have been obvious to a person of ordinary skill in the art to modify the method of Blackwood to include using CO2, as taught by Tomimori et al. for purposes of performing the same function of decreasing the electrostatic charge on the wafer surface.

In reference to claims 2-3 and 27-28, refer to col. 6, lines 5-7 of Blackwood et al. In reference to claims 6 and 30, both Blackwood and Tomimori teaches using ionized nitrogen gas for drying the wafers. In reference to claims 9 and 32 refer to col. 6 and 7 bridging, and col. 7, lines 25-30. In reference to claim 34 refer to the teachings of Tomimori et al.

9. Claims 7, 31 and 36 are rejected under 35 U.S.C. 103(a) as being unpatentable over Blackwood et al. (4132567) in view of Tomimori et al. (US2003/0013310), as applied to claims 1-3, 6, 9, 26-28, 30, 32, and 34, as described in paragraph 8 above and further in view of in view of Tamaki et al. (5227001).

Blackwood et al. teach the invention substantially as claimed with the exception of IPA. Tamaki et al. teach wet stripping followed by drying with nitrogen or IPA to decrease the electrostatic discharge (col. 8, lines 50-62).

It would have been obvious to a person of ordinary skill in the art to modify the

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method of Blackwood to the use of equivalent means such as IPA, as taught by Tamaki et al. for purposes decreasing the electrostatic charge on the wafer surface.

10. Claims 29 and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Blackwood et al. (4132567) in view of Tomimori et al. (US2003/0013310), as applied to claims 1-3, 6, 9, 26-28, 30, 32, and 34, as described in paragraph 8 above and further in view of Kobayashi (US2002/0045328).

Blackwood et al. in view of Tomimori et al. teach the invention substantially as claimed with the exception of the antistatic agent comprising ionized air. Kobayashi teaches a device for the manufacture of semiconductor devices. In the abstract, Kobayashi teaches an ionizer for decreasing static charge in the semiconductor substrate. In paragraphs 3, 227, and 278, Kobayashi teaches blowing ionized air on the substrate to decrease the static charge.

It would have been obvious to a person of ordinary skill in the art to modify the method of Blackwood to include using ionized air, as taught by Kobayashi et al. for purposes of performing the same function of decreasing the electrostatic charge on the wafer surface.

9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Batchelder, Bohon III, teaches using dry air, CO2, nitrogen, argon, oxygen, helium for reducing charge. Tamaki et al. teaches using IPA/N2. Hill et al. teach using ionized nitrogen to reduce the charge. DeLarios et al. teach using IPA, nitrogen, and CO2 to dry the wafer. V erhaverbeke et al. teach dry N2/IPA. Sehgal,

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Jackson, Aoki et al., Brunner et al., Nikon et al., Ito et al., Christenson et al. teach rinsing with CO2 or ionized air and IPA. Sato teach ionized air.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Sharidan Carrillo whose telephone number is 571-272-1297. The examiner can normally be reached on Monday-Friday, 6:00a.m-2:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Barr can be reached on 571-272-1414. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Sharidan Carrillo
Primary Examiner
Art Unit 1746

bsc

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